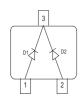


### **Silicon Variable Capacitance Diodes**

- For FM radio tuners with extended frequency band
- High tuning ratio at low supply voltage (car radio)
- Monolithic chip (common cathode) for perfect dual diode tracking
- Coded capacitance groups and group matching available
- Pb-free (RoHS compliant) package







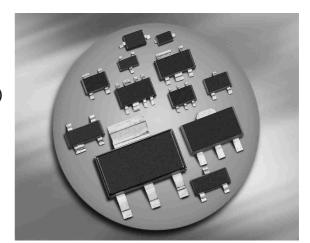
Туре	Package	Configuration	<b>L</b> <sub>S</sub> (nH)	Marking
BB814	SOT23	common cathode	1.8	SH1/2*

<sup>\*</sup>For differences see next page Capacitance groups

## **Maximum Ratings** at $T_A = 25$ °C, unless otherwise specified

Parameter	Symbol	Value	Unit
Diode reverse voltage	$V_{R}$	18	V
Peak reverse voltage-	$V_{RM}$	20	
Forward current	I <sub>F</sub>	50	mA
Operating temperature range	$T_{op}$	-55 12 <b>5</b>	°C
Storage temperature	$T_{\rm stq}$	-55 150	

1





**Electrical Characteristics** at  $T_A = 25$ °C, unless otherwise specified

Parameter	Symbol	Values			Unit
		min.	typ.	max.	]
DC Characteristics	·	•			•
Reverse current	$I_{R}$				nA
V <sub>R</sub> = 16 V		_	-	20	
$V_{R}$ = 16 V, $T_{A}$ = 60 °C		-	-	200	
AC Characteristics					
Diode capacitance <sup>1)</sup>	C <sub>T</sub>				pF
$V_{R} = 2 \text{ V}, f = 1 \text{ MHz}$		43	44.75	46.5	
$V_{R} = 8 \text{ V}, f = 1 \text{ MHz}$		19.1	20.8	22.7	
Capacitance ratio	C <sub>T2</sub> /C <sub>T8</sub>	2.05	2.15	2.25	
$V_{R} = 2 \text{ V}, V_{R} = 8 \text{ V}, f = 1 \text{ MHz}$					
Capacitance matching <sup>2)</sup>	$\Delta C_{T}/C_{T}$	-	-	3	%
$V_{R}$ = 2 V, $V_{R}$ = 8 V, $f$ = 1 MHz					
Series resistance	$r_{\rm S}$	-	0.18	_	Ω
$V_{R}$ = 2 V, $f$ = 100 MHz					
Q factor	Q	-	200	_	
$f = 100 \text{ MHz}, V_{R} = 2 \text{ V}$					

<sup>&</sup>lt;sup>1</sup>Capacitance groups at 2V and 8V, coded 1; 2

 $C_{\mathsf{T}}/\mathsf{groups}$  1 2

 $C_{2V}$  min 43pF 44.5pF  $C_{2V}$  max 45pF 46.5pF  $C_{8V}$  min 19.1pF 19.75pF  $C_{8V}$  max 21.95pF 22.7pF

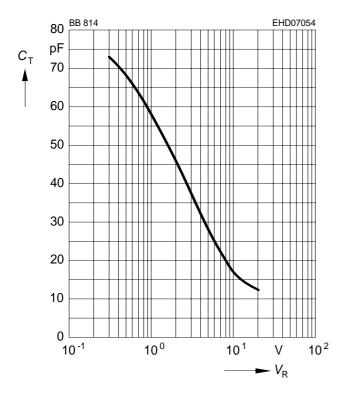
2 2011-06-15

<sup>&</sup>lt;sup>2</sup>For details please refer to Application Note 047.

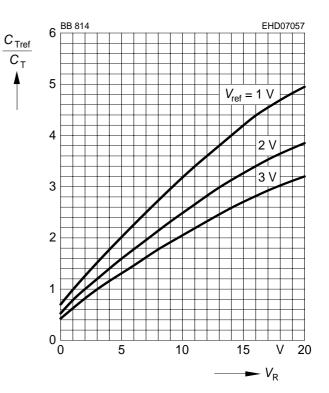


# Diode capacitance $C_T = f(V_R)$

f = 1MHz



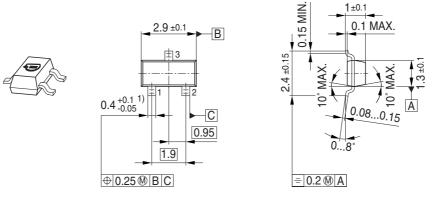
# Capacitance ratio $C_{\text{Tref}}/C_{\text{T}} = f(V_{\text{R}})$ f = 1 MHz



3 2011-06-15

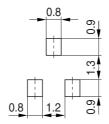


## Package Outline

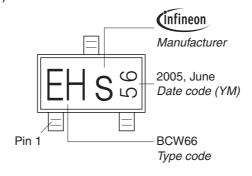


1) Lead width can be 0.6 max. in dambar area

#### Foot Print

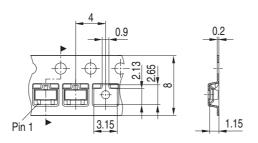


## Marking Layout (Example)



# Standard Packing

Reel ø180 mm = 3.000 Pieces/Reel Reel ø330 mm = 10.000 Pieces/Reel



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